

SMMBT3904LT3G Datasheet

Ма



| DiGi Electronics Part Number | SMMBT3904LT3G-DG |
|------------------------------|--|
| Manufacturer | onsemi |
| Aanufacturer Product Number | SMMBT3904LT3G |
| Description | TRANS NPN 40V 0.2A SOT23-3 |
| Detailed Description | Bipolar (BJT) Transistor NPN 40 V 200 mA 300MHz 3 00 mW Surface Mount SOT-23-3 (TO-236) |
| | |

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Purchase and inquiry

| Manufacturer Product Number: | Manufacturer: |
|--|--|
| SMMBT3904LT3G | onsemi |
| Series: | Product Status: |
| | Active |
| Transistor Type: | Current - Collector (Ic) (Max): |
| NPN | 200 mA |
| Voltage - Collector Emitter Breakdown (Max): | Vce Saturation (Max) @ lb, lc: |
| 40 V | 300mV @ 5mA, 50mA |
| Current - Collector Cutoff (Max): | DC Current Gain (hFE) (Min) @ Ic, Vce: |
| - | 100 @ 10mA, 1V |
| Power - Max: | Frequency - Transition: |
| 300 mW | 300MHz |
| Operating Temperature: | Grade: |
| -55°C ~ 150°C (TJ) | Automotive |
| Qualification: | Mounting Type: |
| AEC-Q101 | Surface Mount |
| Package / Case: | Supplier Device Package: |
| TO-236-3, SC-59, SOT-23-3 | SOT-23-3 (TO-236) |
| Base Product Number: | |
| SMMBT3904 | |
| | |

Environmental & Export classification

8541.21.0075

| RoHS Status: | Moisture Sensitivity Level (MSL): |
|------------------|-----------------------------------|
| ROHS3 Compliant | 1 (Unlimited) |
| REACH Status: | ECCN: |
| REACH Unaffected | EAR99 |
| HTSUS: | |
| | |

NSEM

General Purpose Transistor

NPN Silicon

MMBT3904L, SMMBT3904L

Features

- These Devices are Pb-Free, Halogen Free/BFR Free and are RoHS Compliant
- S Prefix for Automotive and Other Applications Requiring Unique Site and Control Change Requirements; AEC-Q101 Qualified and **PPAP** Capable

MAXIMUM RATINGS

| Rating | Symbol | Value | Unit |
|-----------------------------------|------------------|-------|------|
| Collector – Emitter Voltage | V _{CEO} | 40 | Vdc |
| Collector – Base Voltage | V _{CBO} | 60 | Vdc |
| Emitter – Base Voltage | V _{EBO} | 6.0 | Vdc |
| Collector Current – Continuous | ۱ _C | 200 | mAdc |
| Collector Current – Peak (Note 3) | I _{CM} | 900 | mAdc |

THERMAL CHARACTERISTICS

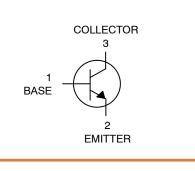
| Characteristic | Symbol | Max | Unit |
|--|-----------------------------------|-------------|-------------|
| Total Device Dissipation FR-5 Board (Note 1) @T _A = 25°C Derate above 25°C | P _D | 225 1.8 | mW mW/°C |
| Thermal Resistance, Junction-to-Ambient | $R_{\theta JA}$ | 556 | °C/W |
| Total Device Dissipation Alumina Substrate, (Note 2) @T _A = 25°C Derate above 25°C | P _D | 300 2.4 | mW mW/°C |
| Thermal Resistance, Junction-to-Ambient | $R_{\theta JA}$ | 417 | °C/W |
| Junction and Storage Temperature | T _J , T _{stg} | -55 to +150 | °C |

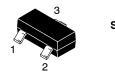
Stresses exceeding those listed in the Maximum Ratings table may damage the device. If any of these limits are exceeded, device functionality should not be assumed, damage may occur and reliability may be affected.

1. FR-5 = $1.0 \times 0.75 \times 0.062$ in.

2. Alumina = $0.4 \times 0.3 \times 0.024$ in. 99.5% alumina.

3. Reference SOA curve.





SOT-23 (TO-236) **CASE 318** STYLE 6

MARKING DIAGRAM



1AM = Specific Device Code Μ = Date Code*

= Pb-Free Package

. (Note: Microdot may be in either location)

*Date Code orientation and/or overbar may vary depending upon manufacturing location.

ORDERING INFORMATION

| Device | Package | Shipping [†] |
|---------------|-----------|-----------------------|
| MMBT3904LT1G | SOT-23 | 3000 / Tape & |
| SMMBT3904LT1G | (Pb-Free) | Reel |
| MMBT3904LT3G | SOT-23 | 10,000 / Tape & |
| SMMBT3904LT3G | (Pb-Free) | Reel |

+For information on tape and reel specifications, including part orientation and tape sizes, please refer to our Tape and Reel Packaging Specifications Brochure, BRD8011/D.

ELECTRICAL CHARACTERISTICS (T_A = 25°C unless otherwise noted)

| Characteristic | Symbol | Min | Мах | Unit |
|--|----------------------|-----|-----|------|
| OFF CHARACTERISTICS | | | | |
| Collector – Emitter Breakdown Voltage ($I_C = 1.0 \text{ mAdc}, I_B = 0$) | V _{(BR)CEO} | 40 | - | Vdc |
| Collector – Base Breakdown Voltage ($I_C = 10 \ \mu Adc$, $I_E = 0$) | V _{(BR)CBO} | 60 | - | Vdc |
| Emitter – Base Breakdown Voltage (I_E = 10 µAdc, I_C = 0) | V _{(BR)EBO} | 6.0 | - | Vdc |
| Base Cutoff Current (V _{CE} = 30 Vdc, V _{EB} = 3.0 Vdc) | I _{BL} | - | 50 | nAdc |
| Collector Cutoff Current (V _{CE} = 30 Vdc, V _{EB} = 3.0 Vdc) | I _{CEX} | _ | 50 | nAdc |

ON CHARACTERISTICS (Note 4)

| $ \begin{array}{l} \text{DC Current Gain} \\ (I_{C} = 0.1 \text{ mAdc, } V_{CE} = 1.0 \text{ Vdc}) \\ (I_{C} = 1.0 \text{ mAdc, } V_{CE} = 1.0 \text{ Vdc}) \\ (I_{C} = 10 \text{ mAdc, } V_{CE} = 1.0 \text{ Vdc}) \\ (I_{C} = 50 \text{ mAdc, } V_{CE} = 1.0 \text{ Vdc}) \\ (I_{C} = 100 \text{ mAdc, } V_{CE} = 1.0 \text{ Vdc}) \\ (I_{C} = 100 \text{ mAdc, } V_{CE} = 1.0 \text{ Vdc}) \end{array} $ | H _{FE} | 40 70 100 60 30 | - 300 - | - |
|---|----------------------|-----------------------------|---------------|-----|
| Collector – Emitter Saturation Voltage ($I_C = 10 \text{ mAdc}, I_B = 1.0 \text{ mAdc}$) ($I_C = 50 \text{ mAdc}, I_B = 5.0 \text{ mAdc}$) | V _{CE(sat)} | - | 0.2 0.3 | Vdc |
| Base – Emitter Saturation Voltage ($I_C = 10 \text{ mAdc}, I_B = 1.0 \text{ mAdc}$) ($I_C = 50 \text{ mAdc}, I_B = 5.0 \text{ mAdc}$) | V _{BE(sat)} | 0.65 - | 0.85 0.95 | Vdc |

SMALL-SIGNAL CHARACTERISTICS

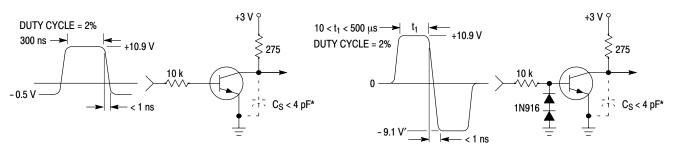
| Current – Gain – Bandwidth Product (I_C = 10 mAdc, V_{CE} = 20 Vdc, f = 100 MHz) | f _T | 300 | - | MHz |
|--|------------------|-----|-----|--------------------|
| Output Capacitance (V _{CB} = 5.0 Vdc, I _E = 0, f = 1.0 MHz) | C _{obo} | - | 4.0 | pF |
| Input Capacitance (V_{EB} = 0.5 Vdc, I_C = 0, f = 1.0 MHz) | C _{ibo} | - | 8.0 | pF |
| Input Impedance (V _{CE} = 10 Vdc, I _C = 1.0 mAdc, f = 1.0 kHz) | h _{ie} | 1.0 | 10 | kΩ |
| Voltage Feedback Ratio (V _{CE} = 10 Vdc, I _C = 1.0 mAdc, f = 1.0 kHz) | h _{re} | 0.5 | 8.0 | X 10 ⁻⁴ |
| Small – Signal Current Gain (V_{CE} = 10 Vdc, I_{C} = 1.0 mAdc, f = 1.0 kHz) | h _{fe} | 100 | 400 | - |
| Output Admittance (V _{CE} = 10 Vdc, I _C = 1.0 mAdc, f = 1.0 kHz) | h _{oe} | 1.0 | 40 | μmhos |
| Noise Figure (V _{CE} = 5.0 Vdc, I _C = 100 μ Adc, R _S = 1.0 k ohms, f = 1.0 kHz) | NF | - | 5.0 | dB |

SWITCHING CHARACTERISTICS

| Delay Time | (V _{CC} = 3.0 Vdc, V _{BE} = -0.5 Vdc, | t _d | - | 35 | 20 |
|--------------|--|----------------|---|-----|----|
| Rise Time | $I_{\rm C} = 10$ mAdc, $I_{\rm B1} = 1.0$ mAdc) | t _r | - | 35 | ns |
| Storage Time | (V _{CC} = 3.0 Vdc, | t _s | - | 200 | 20 |
| Fall Time | $I_{\rm C} = 10 \text{ mAdc}, I_{\rm B1} = I_{\rm B2} = 1.0 \text{ mAdc})$ | t _f | _ | 50 | ns |

Product parametric performance is indicated in the Electrical Characteristics for the listed test conditions, unless otherwise noted. Product performance may not be indicated by the Electrical Characteristics if operated under different conditions.

4. Pulse Test: Pulse Width \leq 300 μ s, Duty Cycle \leq 2.0%.



* Total shunt capacitance of test jig and connectors

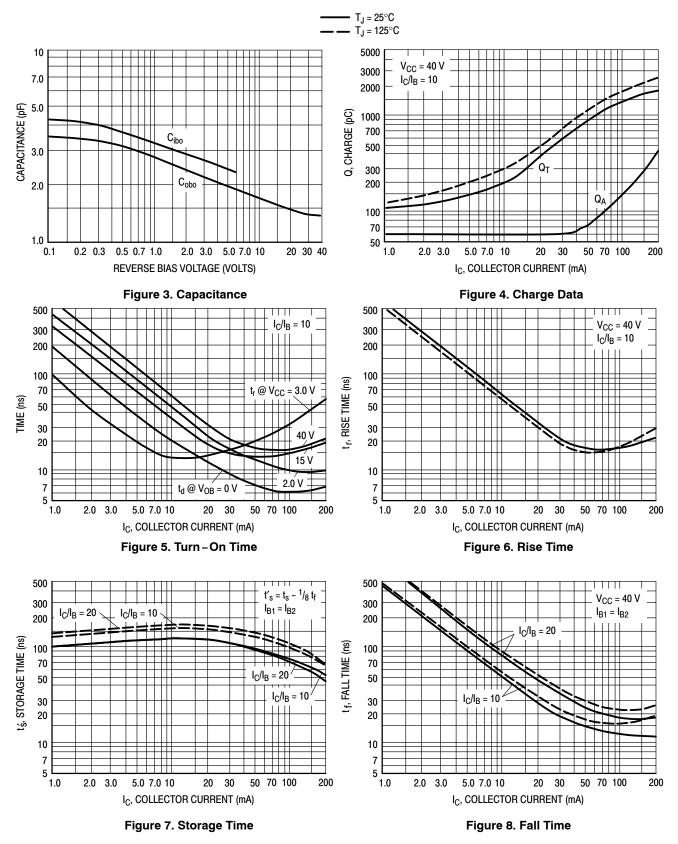
Figure 1. Delay and Rise Time **Equivalent Test Circuit**

Figure 2. Storage and Fall Time Equivalent Test Circuit



2

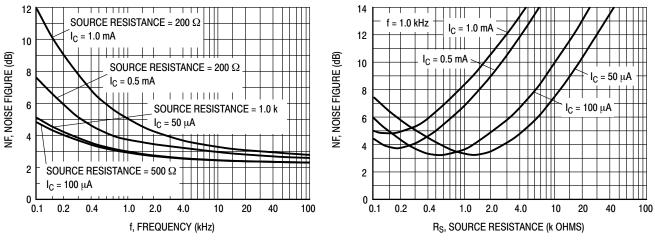
TYPICAL TRANSIENT CHARACTERISTICS





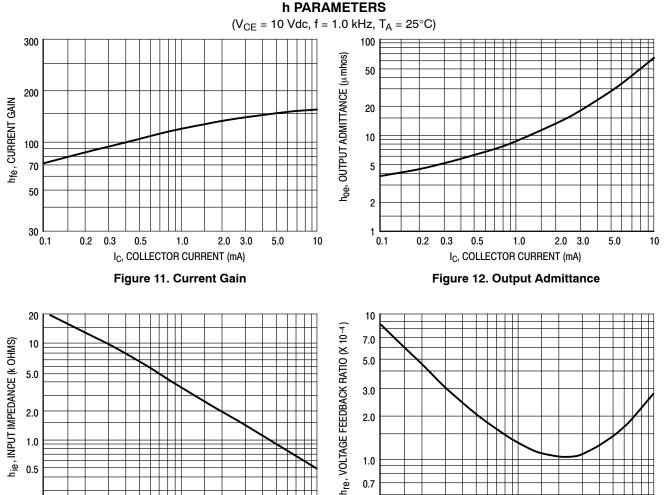
TYPICAL AUDIO SMALL-SIGNAL CHARACTERISTICS NOISE FIGURE VARIATIONS

(V_{CE} = 5.0 Vdc, T_A = 25°C, Bandwidth = 1.0 Hz)









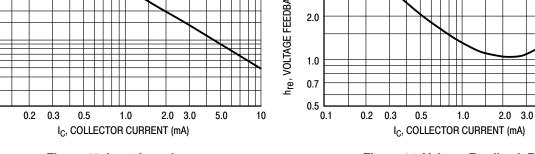


Figure 13. Input Impedance

1.0

0.5

0.2

0.1

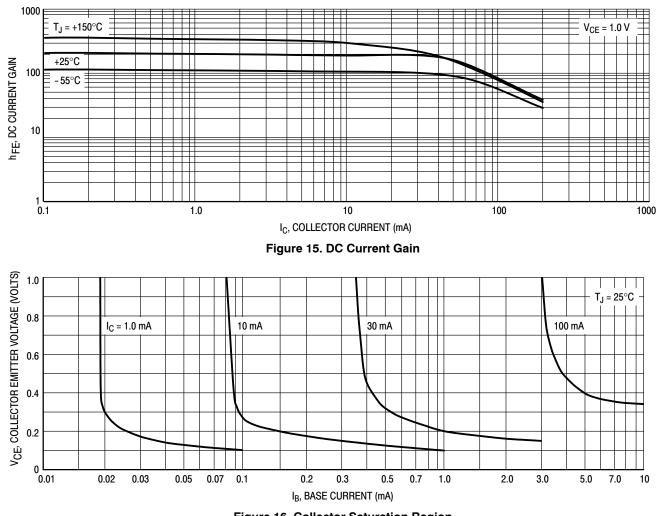
Figure 14. Voltage Feedback Ratio

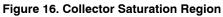


5.0

10

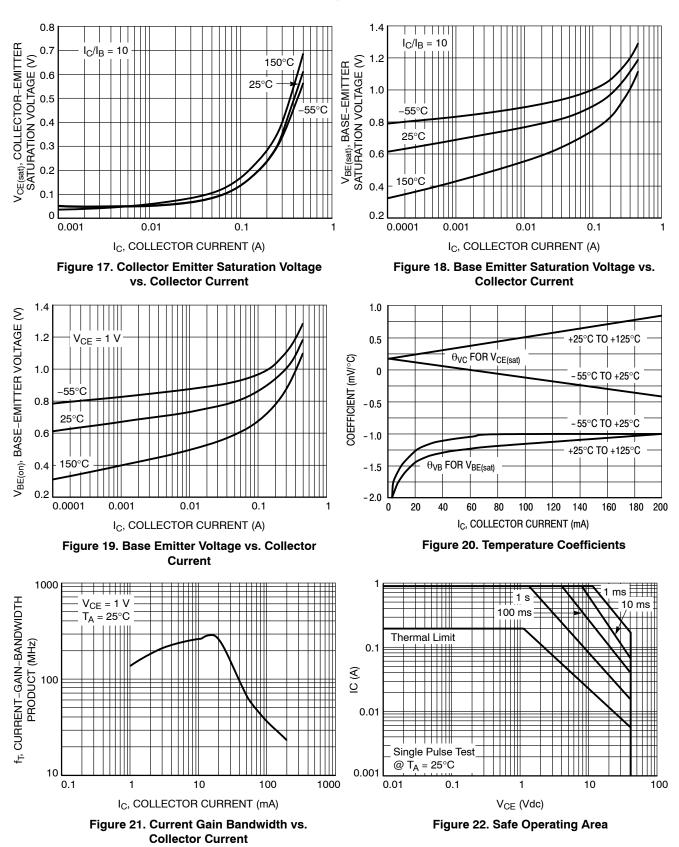
TYPICAL STATIC CHARACTERISTICS







MMBT3904L, SMMBT3904L







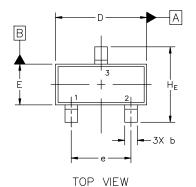
MECHANICAL CASE OUTLINE

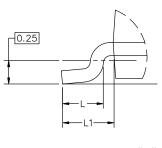
PACKAGE DIMENSIONS



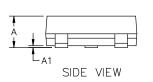
SOT-23 (TO-236) 2.90x1.30x1.00 1.90P **CASE 318 ISSUE AU**

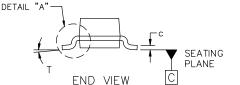
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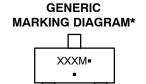








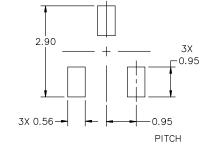




XXX = Specific Device Code М = Date Code

= Pb-Free Package .

*This information is generic. Please refer to device data sheet for actual part marking. Pb-Free indicator, "G" or microdot "•", may or may not be present. Some products may not follow the Generic Marking.



| MILLIMETERS | | | | | |
|-------------|------|------|------|--|--|
| DIM | MIN | NOM | МАХ | | |
| А | 0.89 | 1.00 | 1.11 | | |
| A1 | 0.01 | 0.06 | 0.10 | | |
| b | 0.37 | 0.44 | 0.50 | | |
| С | 0.08 | 0.14 | 0.20 | | |
| D | 2.80 | 2.90 | 3.04 | | |
| E | 1.20 | 1.30 | 1.40 | | |
| е | 1.78 | 1.90 | 2.04 | | |
| L | 0.30 | 0.43 | 0.55 | | |
| L1 | 0.35 | 0.54 | 0.69 | | |
| Ηe | 2.10 | 2.40 | 2.64 | | |
| Т | 0° | | 10° | | |

NOTES:

DIMENSIONING AND TOLERANCING PER ASME Y14.5M, 2018. CONTROLLING DIMENSIONS: 1.

2. MILLIMETERS.

MILLIMETERS. MAXIMUM LEAD THICKNESS INCLUDES LEAD FINISH. MINIMUM LEAD THICKNESS IS THE MINIMUM THICKNESS OF THE BASE MATERIAL. DIMENSIONS D AND E DO NOT INCLUDE MOLD FLASH, PPOTPUSIONS OR GATE BURRS. 3.

4. PROTRUSIONS, OR GATE BURRS.

RECOMMENDED MOUNTING FOOTPRINT

* For additional information on our Pb-Free strategy and soldering details, please download the onsemi Soldering and Mounting Techniques Reference Manual, SOLDERRM/D.

STYLES ON PAGE 2

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DATE 14 AUG 2024

| STYLE 1 THRU 5: CANCELLED | STYLE 6: PIN 1. BASE 2. EMITTER 3. COLLECTOR | STYLE 7: PIN 1. EMITTER 2. BASE 3. COLLECTOR | STYLE 8: PIN 1. ANODE 2. NO CONNECTION 3. CATHODE | ı | |
|---|---|---|--|------------------|------------------|
| STYLE 9: | STYLE 10: | STYLE 11: | STYLE 12: | STYLE 13: | STYLE 14: |
| PIN 1. ANODE | PIN 1. DRAIN | PIN 1. ANODE | PIN 1. CATHODE | PIN 1. SOURCE | PIN 1. CATHODE |
| 2. ANODE | 2. SOURCE | 2. CATHODE | 2. CATHODE | 2. DRAIN | 2. GATE |
| 3. CATHODE | 3. GATE | 3. CATHODE-ANODE | 3. ANODE | 3. GATE | 3. ANODE |
| STYLE 15: | STYLE 16: | STYLE 17: | STYLE 18: | STYLE 19: | STYLE 20: |
| PIN 1. GATE | PIN 1. ANODE | PIN 1. NO CONNECTION | PIN 1. NO CONNECTION | I PIN 1. CATHODE | PIN 1. CATHODE |
| 2. CATHODE | 2. CATHODE | 2. ANODE | 2. CATHODE | 2. ANODE | 2. ANODE |
| 3. ANODE | 3. CATHODE | 3. CATHODE | 3. ANODE | 3. CATHODE-ANODE | 3. GATE |
| STYLE 21: | STYLE 22: | STYLE 23: | STYLE 24: | STYLE 25: | STYLE 26: |
| PIN 1. GATE | PIN 1. RETURN | PIN 1. ANODE | PIN 1. GATE | PIN 1. ANODE | PIN 1. CATHODE |
| 2. SOURCE | 2. OUTPUT | 2. ANODE | 2. DRAIN | 2. CATHODE | 2. ANODE |
| 3. DRAIN | 3. INPUT | 3. CATHODE | 3. SOURCE | 3. GATE | 3. NO CONNECTION |
| STYLE 27: PIN 1. CATHODE 2. CATHODE 3. CATHODE | STYLE 28: PIN 1. ANODE 2. ANODE 3. ANODE | | | | |

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